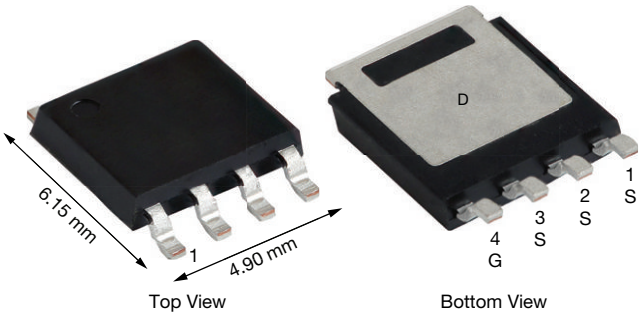
Automotive N-Channel 30 V (D-S) 175 °C MOSFET

PowerPAK® SO-8L



Top View | Bottom View

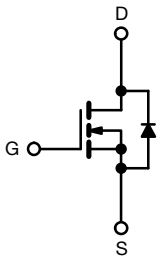
FEATURES

- TrenchFET® Gen IV power MOSFET
- AEC-Q101 qualified
- 100 % R_g and UIS tested
- Q_{gd}/Q_{gs} ratio < 1 optimizes switching characteristics
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

AUTOMOTIVE GRADE

RoHS COMPLIANT

HALOGEN FREE



N-Channel MOSFET

PRODUCT SUMMARY	
V_{DS} (V)	30
$R_{DS(on)}$ (Ω) at V_{GS} = 10 V	0.00325
$R_{DS(on)}$ (Ω) at V_{GS} = 4.5 V	0.00500
I_D (A) [e]	101
Configuration	Single

ORDERING INFORMATION	
Package	PowerPAK® SO-8L
Lead (Pb)-free and halogen-free	SQJ122ELP (for detailed order number please see www.vishay.com/doc?79771)

ABSOLUTE MAXIMUM RATINGS (T_C = 25 °C, unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNIT
Drain-source voltage		V_{DS}	30	V
Gate-source voltage		V_{GS}	± 20	
Continuous drain current [e]	T_C = 25 °C	I_D	101	A
	T_C = 125 °C		58	
Continuous source current (diode conduction) [e]		I_S	55	
Pulsed drain current [a]		I_{DM}	350	
Single pulse avalanche current	L = 0.1 mH	I_{AS}	23	
Single pulse avalanche energy		E_{AS}	26	mJ
Maximum power dissipation [a, e]	T_C = 25 °C	P_D	60	W
	T_C = 125 °C		20	
Operating junction and storage temperature range		T_J, T_{stg}	-55 to +175	°C
Soldering recommendations (peak temperature) [c]			260	

THERMAL RESISTANCE RATINGS

PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient	PCB mount [b]	R_{thJA}	42	°C/W
Junction-to-case (drain) [d]		R_{thJC}	2.5	

Notes

a. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %

b. When mounted on 1" square PCB (FR4 material)

c. See solder profile (www.vishay.com/doc?73257). The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection

d. As per JESD51-14

e. Values based on R_{thJC} and T_C of 25 °C.Actual values achievable will be dependent on the thermal characteristics of the complete system

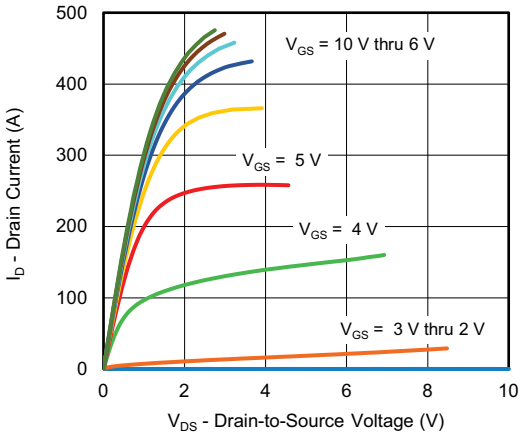
SPECIFICATIONS (T_C = 25 °C, unless otherwise noted)							
PARAMETER	**SYMBOL**	**TEST CONDITIONS**		**MIN.**	**TYP.**	**MAX.**	**UNIT**
Static							
Drain-source breakdown voltage	V_{DS}	V_{GS} = 0, I_D = 250 µA		30	-	-	V
Gate-source threshold voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 250 µA		1.5	2.0	2.5	
Gate-source leakage	I_{GSS}	V_{DS} = 0 V, V_{GS} = ± 20 V		-	-	± 100	nA
Zero gate voltage drain current	I_{DSS}	V_{GS} = 0 V	V_{DS} = 30 V	-	-	1	µA
		V_{GS} = 0 V	V_{DS} = 30 V, T_J = 125 °C	-	-	50	
		V_{GS} = 0 V	V_{DS} = 30 V, T_J = 175 °C	-	-	250	
On-state drain current [a]	$I_{D(on)}$	V_{GS} = 10 V	V_{DS} ≥ 5 V	30	-	-	A
Drain-source on-state resistance [a]	$R_{DS(on)}$	V_{GS} = 10 V	I_D = 15 A	-	0.0027	0.00325	Ω
		V_{GS} = 10 V	I_D = 15 A, T_J = 125 °C	-	-	0.0050	
		V_{GS} = 10 V	I_D = 15 A, T_J = 175 °C	-	-	0.0060	
		V_{GS} = 4.5 V	I_D = 15 A	-	0.0040	0.0050	
Forward transconductance [b]	g_{fs}	V_{DS} = 15 V, I_D = 40 A		-	110	-	S
Dynamic [b]							
Input capacitance	C_{iss}	V_{GS} = 0 V	V_{DS} = 25 V, f = 1 MHz	-	1998	2798	pF
Output capacitance	C_{oss}			-	735	1029	
Reverse transfer capacitance	C_{rss}			-	108	152	
Total gate charge [c]	Q_g	V_{GS} = 10 V	V_{DS} = 15 V, I_D = 6 A	-	33	51	nC
Gate-source charge [c]	Q_{gs}			-	6	-	
Gate-drain charge [c]	Q_{gd}			-	6	-	
Gate resistance	R_g	f = 1 MHz		1.2	3.02	4.8	Ω
Turn-on delay time [c]	$t_{d(on)}$	V_{DD} = 15 V, R_L = 1 Ω I_D ≅ 6 A, V_{GEN} = 10 V, R_g = 1 Ω		-	11	17	ns
Rise time [c]	t_r			-	5	9	
Turn-off delay time [c]	$t_{d(off)}$			-	28	42	
Fall time [c]	t_f			-	9	14	
Source-Drain Diode Ratings and Characteristics [b]							
Pulsed current [a]	I_{SM}			-	-	220	A
Forward voltage	V_{SD}	I_F = 15 A, V_{GS} = 0 V		-	-	1.1	V
Body diode reverse recovery time	t_{rr}	I_F = 10 A, di/dt = 100 A/µs		-	33	66	ns
Body diode reverse recovery charge	Q_{rr}			-	16	34	nC
Reverse recovery fall time	t_a			-	13	-	ns
Reverse recovery rise time	t_b			-	21	-	
Body diode peak reverse recovery current	$I_{RM(REC)}$			-	-0.85	-	A

Notes

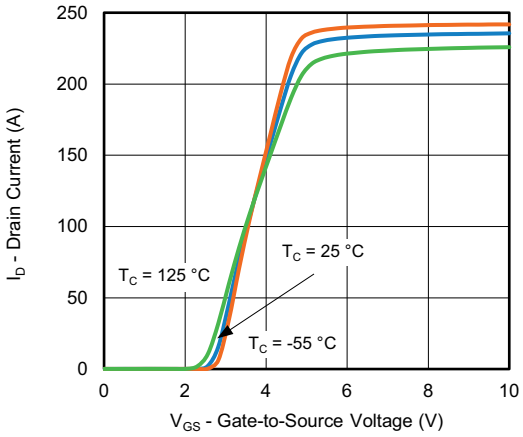
a. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %
b. Guaranteed by design, not subject to production testing
c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

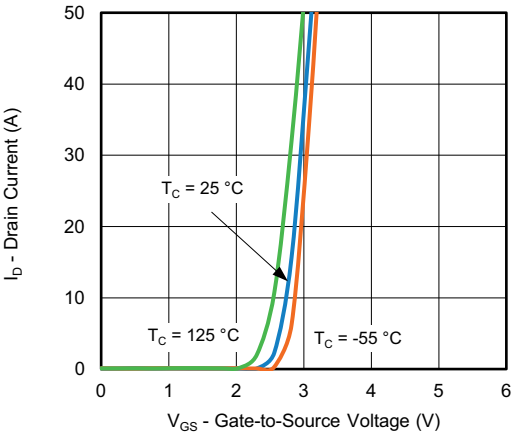
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



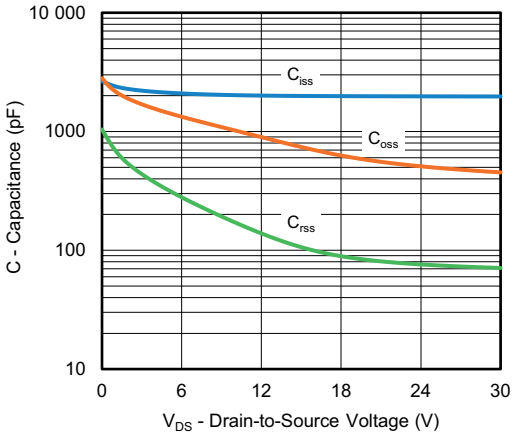
Output Characteristics



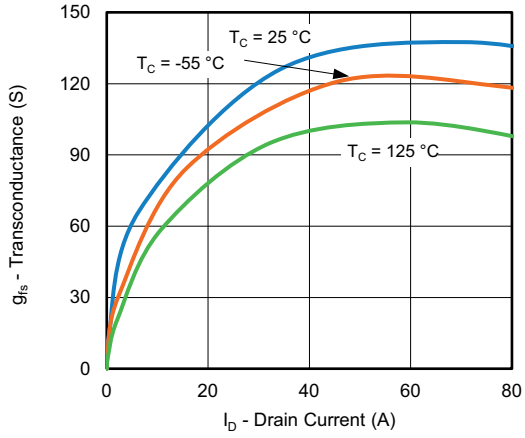
Transfer Characteristics



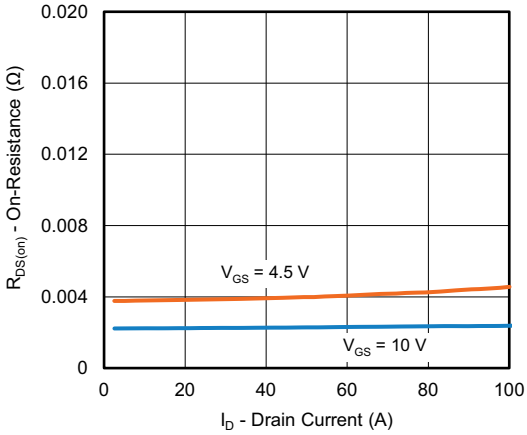
Transfer Characteristics



Capacitance

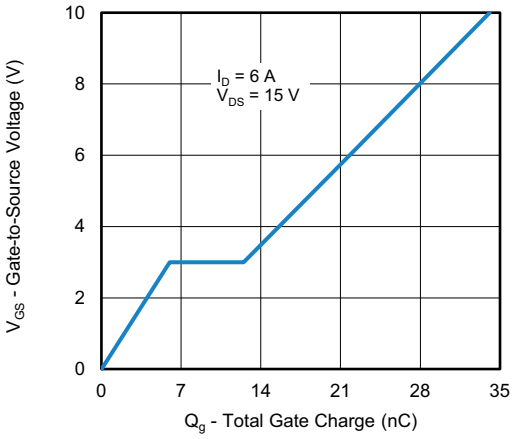


Transconductance

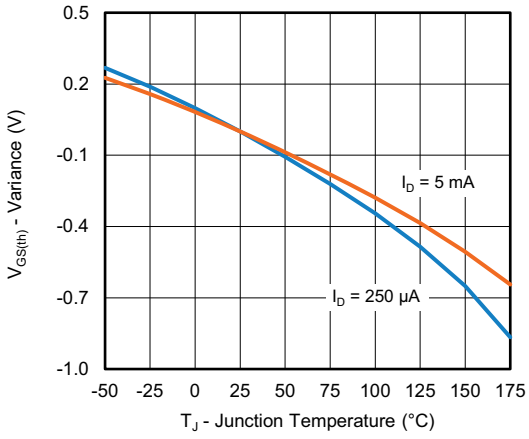


On-Resistance vs. Drain Current

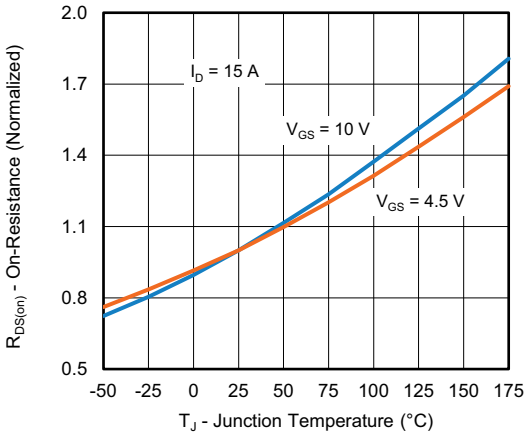
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



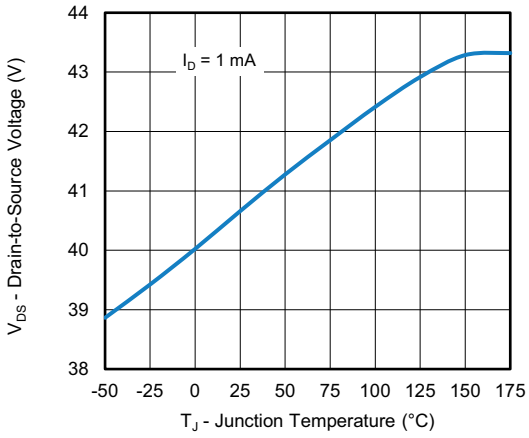
Gate Charge



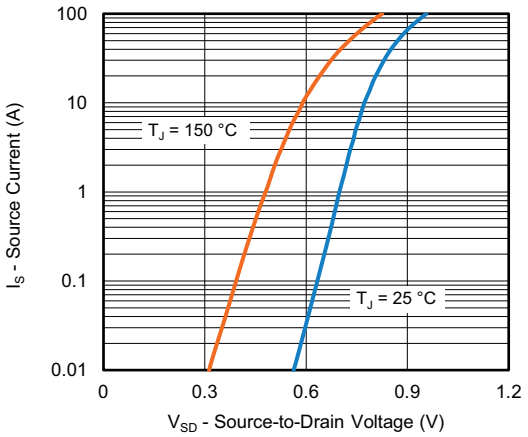
Threshold Voltage



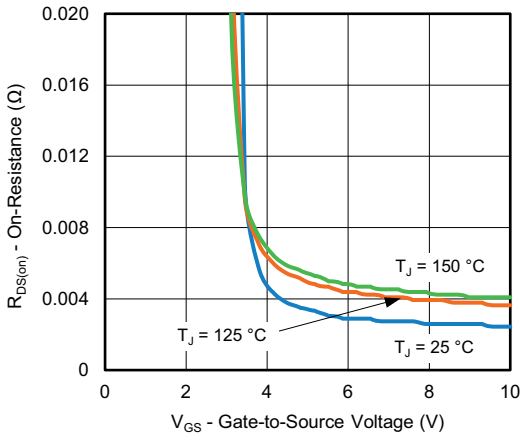
On-Resistance vs. Junction Temperature



Drain Source Breakdown vs. Junction Temperature

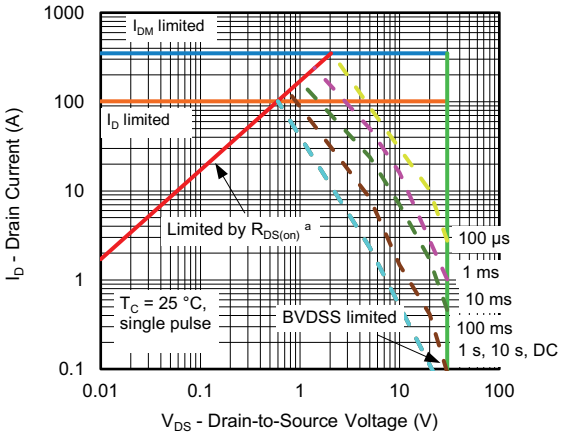


Source Drain Diode Forward Voltage



On-Resistance vs. Gate-to Source Voltage

TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

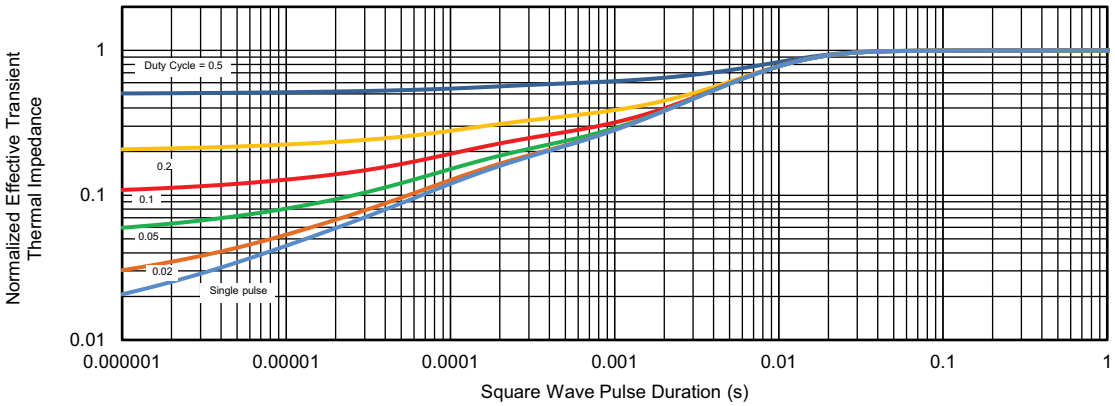


Safe Operating Area

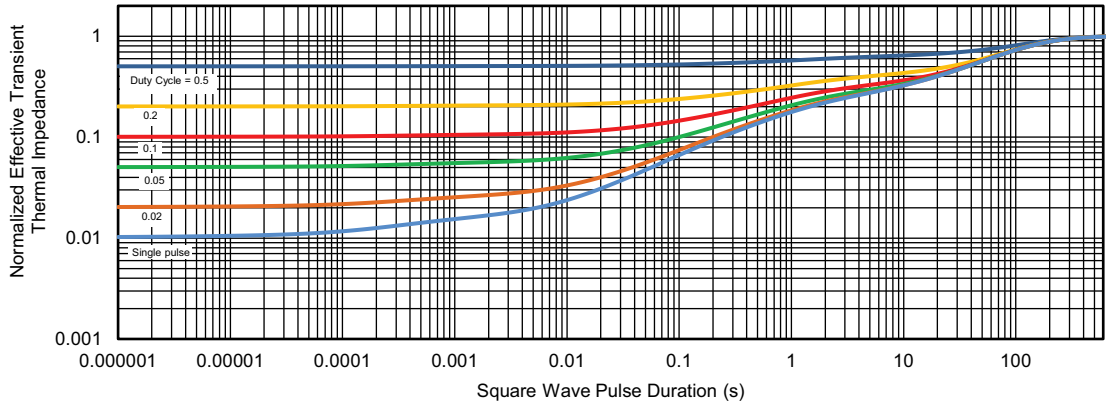
Note

a. V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified

TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case



Normalized Thermal Transient Impedance, Junction-to-Ambient

Note

- The characteristics shown in the two graphs
  - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
  - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

  are given for general guidelines only to enable the user to get a “ball park” indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

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